TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

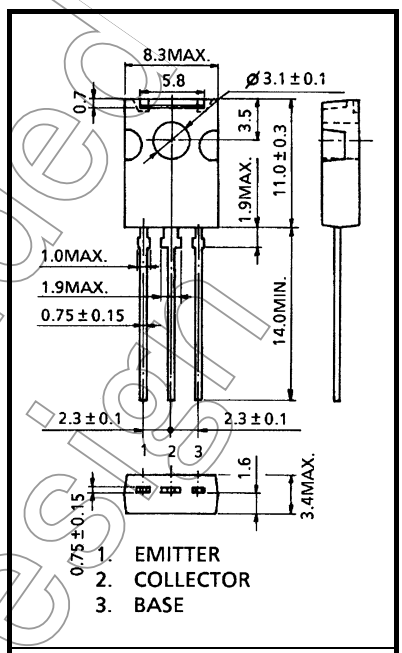
2SC3420

Strobe Flash Applications

Audio Power Amplifier Applications

- High DC current gain : h_{FE} = 140 to 600 (V_{CE} = 2 V, I_C = 0.5 A)
  : h_{FE} = 70 (min) (V_{CE} = 2 V, I_C = 4 A)
- Low saturation voltage: $V_{CE\ (sat)}$ = 1.0 V (max) (I_C = 4 A, I_B = 0.1 A)
- High collector power dissipation: P_C = 10 W (T_c = 25°C),
  P_C = 1.5 W (T_a = 25°C)

Unit: mm



JEDEC	—
JEITA	—
TOSHIBA	2-8H1A

Weight: 0.82 g (typ.)

Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit
Collector-base voltage		V_{CBO}	50	V
Collector-emitter voltage		V_{CES}	40	V
		V_{CEO}	20	
Emitter-base voltage		V_{EBO}	8	V
Collector current	DC	I_C	5	A
	Pulse (Note 1)	I_{CP}	8	
Base current		I_B	1	A
Collector power dissipation	Ta = 25°C	P_C	1.5	W
	Tc = 25°C		10	
Junction temperature		T_j	150	°C
Storage temperature range		T_{stg}	−55 to 150	°C

Note 1: Pulse test: Pulse width = 10 ms (max) Duty cycle = 30% (max)

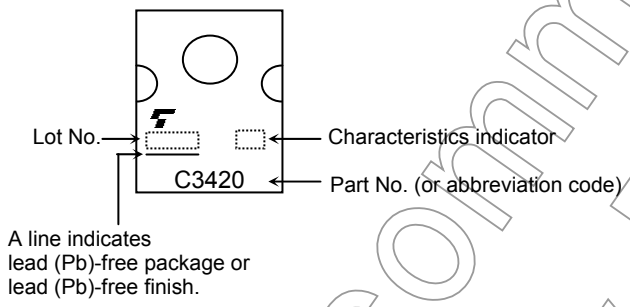
Note 2: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Electrical Characteristics (Tc = 25°C)

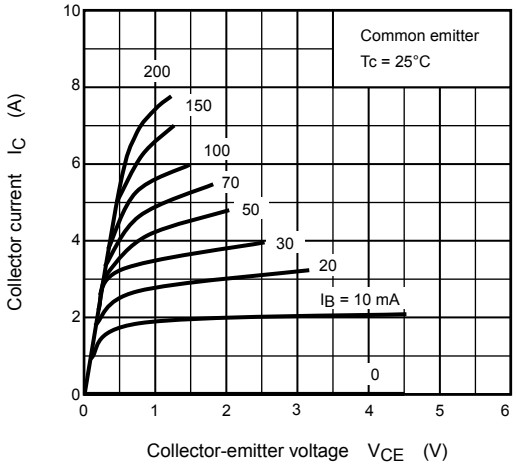
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	I_{CBO}	V_{CB} = 40 V, I_E = 0	—	—	100	nA
Emitter cut-off current	I_{EBO}	V_{EB} = 8 V, I_C = 0	—	—	100	nA
Collector-emitter breakdown voltage	$V_{(BR)\ CEO}$	I_C = 10 mA, I_B = 0	20	—	—	V
DC current gain	$h_{FE\ (1)}$ (Note 3)	V_{CE} = 2 V, I_C = 0.5 A	140	—	600	
	$h_{FE\ (2)}$	V_{CE} = 2 V, I_C = 4 A	70	—	—	
Collector-emitter saturation voltage	$V_{CE\ (sat)}$	I_C = 4 A, I_B = 0.1 A	—	—	1.0	V
Base-emitter voltage	V_{BE}	V_{CE} = 2 V, I_C = 4 A	—	—	1.5	V
Transition frequency	f_T	V_{CE} = 2 V, I_C = 0.5 A	—	100	—	MHz
Collector output capacitance	C_{ob}	V_{CB} = 10 V, I_E = 0, f = 1 MHz	—	40	—	pF

Note 3: $h_{FE\ (1)}$ classification Y: 140 to 240, GR: 200 to 400, BL: 300 to 600

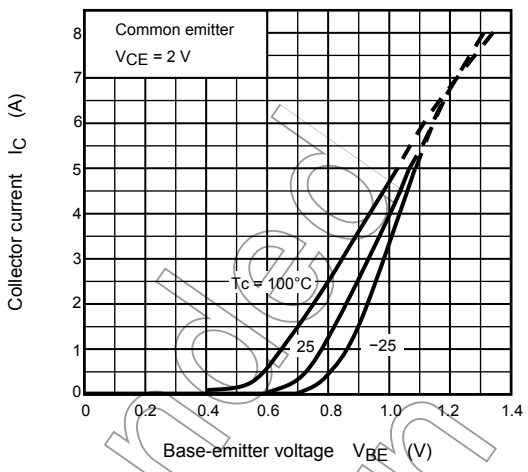
Marking



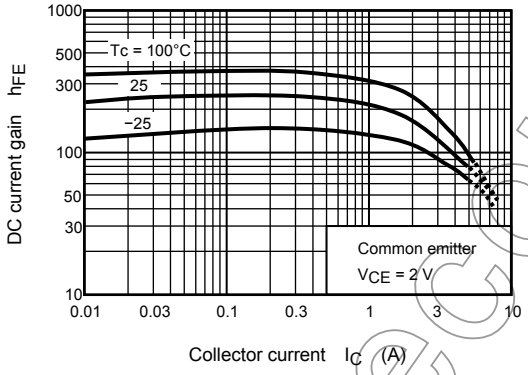
$I_C - V_{CE}$



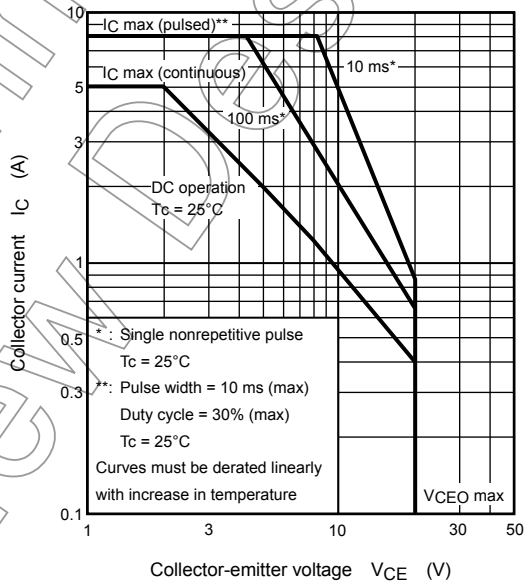
$I_C - V_{BE}$



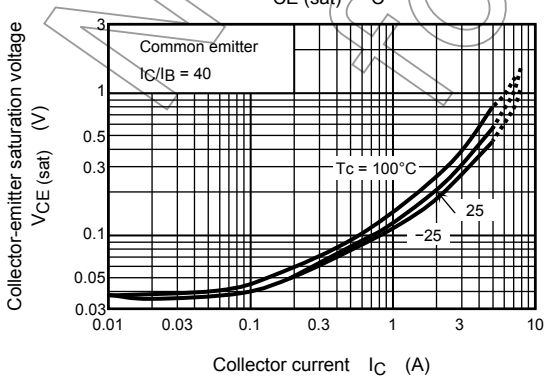
$h_{FE} - I_C$



Safe Operating Area



$V_{CE\ (sat)} - I_C$



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